

NB3F8L3005C

3.3V / 2.5V / 1.8V / 1.5V 1:5 LVC MOS Fanout Buffer

Description

The NB3F8L3005C is a 2:1:5 Clock / Data fanout buffer operating on a 3.3 V / 2.5 V Core V_{DD} and two flexible 3.3 V / 2.5 V / 1.8 V / 1.5 V V_{DDO_x} supplies which must be equal or less than V_{DD} .

A Mux selects between a Crystal input, or a differential/SE Clock / Data inputs. Differential Inputs accept LVPECL, LVDS, HCSL, or SSTL and Single-Ended levels. The MUX control line, SEL selects CLK/ $\overline{\text{CLK}}$, or Crystal input pins per Table 3. The Crystal input is disabled when a Clock input is selected. Output enable pin, OE, synchronously forces a High Impedance state (Hi-Z) when Low per Table 4.

Outputs consist of five single-ended LVC MOS outputs.

Features

- Five LVC MOS / LV TTL Outputs up to 200 MHz
- Differential Inputs Accept LVPECL, LVDS, HCSL, SSTL, or LVC MOS/LV TTL
- Crystal Interface
- Crystal Input Frequency Range: 10 MHz to 50 MHz
- Output Skew: 10 ps Typical
- Additive RMS Phase Jitter @ 156.25 MHz, (12 kHz – 20 MHz): 0.03 ps (Typical)
- Synchronous Output Enable
- Output Defined Level When Input is Floating
- Power Supply Modes:
 - ♦ Single 3.3 V \pm 5%
 - ♦ Single 2.5 V \pm 5%
 - ♦ Mixed 3.3 V \pm 5% Core/2.5 V \pm 5% Output Operating Supply
 - ♦ Mixed 3.3 V \pm 5% Core/1.8 V \pm 0.2 V Output Operating Supply
 - ♦ Mixed 3.3 V \pm 5% Core/1.5 V \pm 0.15 V Output Operating Supply
 - ♦ Mixed 2.5 V \pm 5% Core/ 1.8 V \pm 0.2 V Output Operating Supply
 - ♦ Mixed 2.5 V \pm 5% Core /1.5 V \pm 0.15 V Output Operating Supply
- Two Separate Output Bank Power Supplies
- Industrial Temperature Range: -40°C to 85°C
- These are Pb-Free Devices

Applications

- Clock Distribution
- Networking and Communications
- High End Computing
- Wireless and Wired Infrastructure

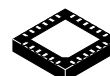
End Products

- Servers
- Ethernet Switch/Routers
- ATE
- Test and Measurement



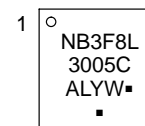
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**QFN24
G SUFFIX
CASE 485DJ**

MARKING DIAGRAM



A	= Assembly Location
L	= Wafer Lot
Y	= Year
W	= Work Week
▪	= Pb-Free Package

(*Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information on page 12 of this data sheet.

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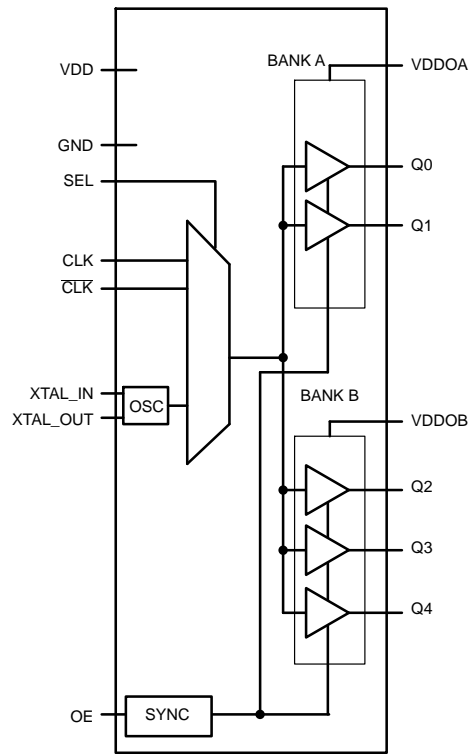


Figure 1. Simplified Logic Diagram

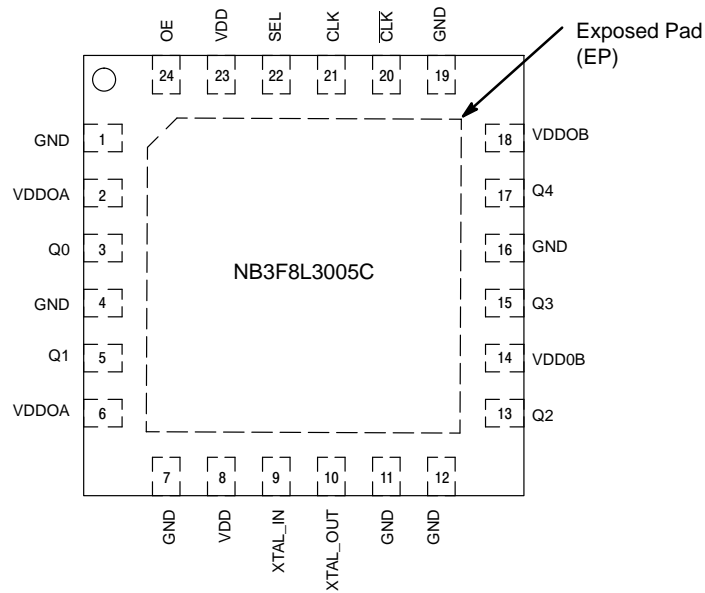


Figure 2. Pinout Configuration (Top View)

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Table 1. PIN DESCRIPTION

Number	Name	Type	Input Default	Description
3, 5	Q0, Q1	LVC MOS		Outputs – Bank A
13, 15, 17	Q2, Q3, Q4	LVC MOS		Outputs – Bank B
2, 6	VDDOA	Power		Positive Supply Pins for Bank A Outputs Q0 – Q1
14, 18	VDDOB	Power		Positive Supply Pins for Bank B Outputs Q2 – Q4
1, 4, 7, 11, 12, 16, 19	GND	GND		Ground Supply
8, 23	VDD	Power		V _{DD} Positive Supply pin for Core and Inputs.
9	XTAL_IN	XTAL OSC / CLK Input		Crystal Oscillator Interface or External Clock Source at LVC MOS Levels
10	XTAL_OUT	XTAL OSC Output		Crystal Interface
20	CLK	Diff / SE Input	Pullup / Pulldown	Inverting differential clock input
21	CLK	Diff / SE Input	Pulldown	Non-inverting clock input
22	SEL	LVC MOS / LV TTL Input	Pulldown	Input clock select. See Table 3 for function. Input Pulldown
24	OE	LVC MOS / LV TTL Input	Pulldown	Output Enable Control. See Table 4 for function.
–	EP	–		The Exposed Pad (EP) on the QFN–24 package bottom is thermally connected to the die for improved heat transfer out of package. The exposed pad must be attached to a heat-sinking conduit. The pad is electrically connected to the die, and must be electrically connected to GND.

1. All VDD, VDDO_x and GND pins must be externally connected to a power supply to guarantee proper operation. Bypass each V_{DD} and VDDO_x with 0.01 μ F CAP to GND.

Table 2. PIN CHARACTERISTICS

Symbol	Parameter	Min	Typ	Max	Unit
C _{IN}	Input Capacitance		4		pF
R _{PU}	Input Pullup Resistor		50		k Ω
R _{PD}	Input Pulldown Resistor		50		k Ω
C _{PD}	Power Dissipation Capacitance (per output) VDDO = 3.3 V VDDO = 2.5 V VDDO = 1.8 V VDDO = 1.5 V				pF
R _{OUT}	Output Impedance VDDO = 3.3 V VDDO = 2.5 V VDDO = 1.8 V VDDO = 1.5 V		20		Ω

FUNCTION TABLES

Table 3. CLOCK ENABLE (SELx) FUNCTION TABLE

SEL Input	Selected Input Clock
0	CLK/CLK
1	Crystal Osc Input

Table 4. CLOCK OUTPUT ENABLE (OE) FUNCTION TABLE

OE Input	Q _n Outputs
0	Disabled, High Impedance
1	Outputs Enabled

Table 5. CLK INPUT VS. OUTPUT STATUS

Input Condition	Output
CLK/CLK = OPEN	Logic LOW
CLK/CLK = GND	Undefined
CLK = HIGH; CLK = LOW	Logic HIGH
CLK = LOW; CLK = HIGH	Logic LOW

Table 6. CRYSTAL CHARACTERISTICS

Parameter	Min	Typ	Max	Unit
Mode of Oscillation	Fundamental			
Frequency	10		50	MHz
Equivalent Series Resistance (ESR)			50	Ω
Shunt Capacitance			7	pF
Drive Power			100	μW

Table 7. ATTRIBUTES

Characteristic	Value
ESD Protection Human Body Model Machine Model	>2 kV 200 V
Moisture Sensitivity (Note 2) QFN24	Level 3
Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in
Transistor Count	474
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test	

2. For additional information, see Application Note AND8003/D.

Table 8. MAXIMUM RATINGS (Note 3)

Symbol	Parameter	Condition	Rating	Unit
V _{DD} , V _{DDO_x}	Positive Power Supply	GND = 0 V	4.6	V
V _I	Input Voltage XTAL_IN Diff, SELx, OE Inputs		0 ≤ V _I ≤ V _{DD} -0.5 ≤ V _I ≤ V _{DD} + 0.5	V
V _O	Output Voltage		-0.5 ≤ V _O ≤ V _{DDO_x} + 0.5	V
T _{stg}	Storage Temperature Range		-65 to +150	°C
θ _{JA}	Thermal Resistance (Junction-to-Ambient)	QFN24 QFN24	0 lfpm 500 lfpm	°C/W
θ _{JC}	Thermal Resistance (Junction-to-Case)	QFN24	(Note 3)	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

3. JEDEC standard multilayer board – 2S2P (2 signal, 2 power).

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Table 9. POWER SUPPLY CHARACTERISTICS $V_{DD} \geq V_{DDO}$; $V_{DD} = 3.3 \text{ V} \pm 5\%$ (3.135 V to 3.465 V) or $V_{DD} = 2.5 \text{ V} \pm 5\%$ (2.375 V to 2.625 V) and $V_{DDOx} = 3.3 \text{ V} \pm 5\%$ (3.135 V to 3.465 V) or $2.5 \text{ V} \pm 5\%$ (2.375 V to 2.625 V) or $1.8 \text{ V} \pm 0.2 \text{ V}$ (1.6 V to 2.0 V) or $1.5 \text{ V} \pm 0.15 \text{ V}$ (1.35 V to 1.65 V); $T_A = -40^\circ\text{C}$ to 85°C

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
I_{DD}	V_{DD} Power Supply Current	$f_{IN} = 0 \text{ MHz}$ $V_{DDO} = 3.3 \text{ V}$, $f_{IN} = 100 \text{ MHz}$ $V_{DDO} = 2.5 \text{ V}$, $f_{IN} = 100 \text{ MHz}$		30 30 20	38	mA
I_{DDO}	V_{DDO} Power Supply Current	OE = 0, no load $V_{DDO} = 3.3 \text{ V}$, OE = 1, $f_{IN} = 100 \text{ MHz}$ $V_{DDO} = 2.5 \text{ V}$, OE = 1, $f_{IN} = 100 \text{ MHz}$		0.1 7 5		mA
$I_{DD} + I_{DDO}$	Total Device Current with Loads on All Outputs	OE = 1, $f_{IN} = 100 \text{ MHz}$ OE = 0		48 16		mA

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

Table 10. DC CHARACTERISTICS $T_A = -40^\circ\text{C}$ to 85°C

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V_{IH}	LVC MOS / LV TTL Input High Voltage (OE, SEL)	$V_{DD} = 3.3 \text{ V} \pm 5\%$ $V_{DD} = 2.5 \text{ V} \pm 5\%$	1.6 1.3		$V_{DD} + 0.3$ $V_{DD} + 0.3$	V
V_{IL}	LVC MOS / LV TTL Input Low Voltage (OE, SEL)	$V_{DD} = 3.3 \text{ V} \pm 5\%$ $V_{DD} = 2.5 \text{ V} \pm 5\%$	-0.3 -0.3		0.8 0.4	V
I_{IH}	Input High Current OE, SEL CLK/CLK	$V_{DD} = V_{IN} = 3.465 \text{ V}$ $V_{DD} = V_{IN} = 3.465 \text{ V}$ or 2.625 V			100 100	μA
I_{IL}	Input Low Current OE, SEL CLK CLK	$V_{DD} = 3.465 \text{ V}$; $V_{IN} = 0.0 \text{ V}$ $V_{DD} = 3.465 \text{ V}$ or 2.625 V ; $V_{IN} = 0.0 \text{ V}$ $V_{DD} = 3.465 \text{ V}$ or 2.625 V ; $V_{IN} = 0.0 \text{ V}$	-5 -5 -150		5	μA
V_{OH}	Output High Voltage		V_{DDO} -0.1			V
V_{OL}	Output Low Voltage	$V_{DDOx} = 3.3 \text{ V} \pm 5\%$ or $2.5 \text{ V} \pm 5\%$			0.5	V
		$V_{DDOx} = 1.8 \text{ V} \pm 0.2 \text{ V}$			0.4	
		$V_{DDOx} = 1.5 \text{ V} \pm 0.15 \text{ V}$			0.37	
V_{PP}	Peak-to-Peak Input Voltage $V_{IL} > -0.3 \text{ V}$ CLKx/CLKx	$V_{DD} = 3.3 \text{ V} \pm 5\%$ or $V_{DD} = 2.5 \text{ V} \pm 5\%$	0.15		1.3	V
V_{IHCMR}	Input High Level Common Mode Range $V_{CM} = V_{IH}$; $V_{IL} > -0.3 \text{ V}$ CLKx/CLKx	$V_{DD} = 3.3 \text{ V} \pm 5\%$ or $V_{DD} = 2.5 \text{ V} \pm 5\%$	0.5		$V_{DD} - 0.85$	V

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

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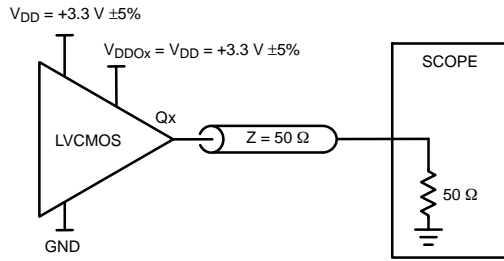
Table 11. AC CHARACTERISTICS $V_{DD} \geq V_{DDO}$; $V_{DD} = 3.3 \text{ V} \pm 5\%$ (3.135 V to 3.465 V) or $V_{DD} = 2.5 \text{ V} \pm 5\%$ (2.375 V to 2.625 V) and $V_{DDOx} = 3.3 \text{ V} \pm 5\%$ (3.135 V to 3.465 V) or $2.5 \text{ V} \pm 5\%$ (2.375 V to 2.625 V) or $1.8 \text{ V} \pm 0.2 \text{ V}$ (1.6 V to 2.0 V) or $1.5 \text{ V} \pm 0.15 \text{ V}$ (1.35 V to 1.65 V); $T_A = -40^\circ\text{C}$ to 85°C

Symbol	Parameter		Test Conditions	Min	Typ	Max	Unit		
f _{MAX}	Output Frequency	Using External Crystal		10		50	MHz		
		Using External Clock Source (Note 4)		DC		200	MHz		
t _{sk(o)}	Output Skew (Notes 5 and 6)				10	25	ps		
t _{JITTERΦ}	Additive RMS Phase Jitter (Integrated 12 kHz – 20 MHz) f _C = 156.25 MHz	Input clock from CLK/CLK	V _{DDOx} = 3.3 V ± 5%		0.03		ps		
			V _{DDOx} = 2.5 V ± 5%		0.03				
			V _{DDOx} = 1.8 V ± 0.2 V		0.03				
			V _{DDOx} = 1.5 V ± 0.15 V		0.03				
		External clock over drives crystal interface	V _{DDOx} = 3.3 V ± 5%		0.03				
			V _{DDOx} = 2.5 V ± 5%		0.03				
			V _{DDOx} = 1.8 V ± 0.2 V		0.03				
			V _{DDOx} = 1.5 V ± 0.15 V		0.03				
		Input clock from crystal	V _{DDOx} = 3.3 V ± 5%		0.03				
			V _{DDOx} = 2.5 V ± 5%		0.03				
			V _{DDOx} = 1.8 V ± 0.2 V		0.03				
			V _{DDOx} = 1.5 V ± 0.15 V		0.03				
t _R / t _F	Output Rise/Fall Time (20% and 80%) C _L = 10 pF	V _{DDOx} = 3.3 V ± 5%	150	350	500	ps			
		V _{DDOx} = 2.5 V ± 5%	150	350	500				
		V _{DDOx} = 1.8 V ± 0.2 V	150	350	600				
		V _{DDOx} = 1.5 V ± 0.15 V	150	350	600				
odc	Output Duty Cycle	V _{DDOx} = 3.3 V ± 5%	45		55	%			
		V _{DDOx} = 2.5 V ± 5%	40		60				
		V _{DDOx} = 1.8 V ± 0.2 V	40		60				
		V _{DDOx} = 1.5 V ± 0.15 V	40		60				
PSRR	Power Supply Ripple Rejection		100 kHz, 100 mV _{PP} Ripple Injected on V _{DD} , V _{DDO} = 2.5 V		–44		dBc		
t _{EN}	Output Enable Time (Note 7)	OE				4	cycles		
t _{DIS}	Output Disable Time (Note 7)	OE				4	cycles		
MUX_ISOLATION	MUX_ISOLATION		155.52 MHz	55			dB		

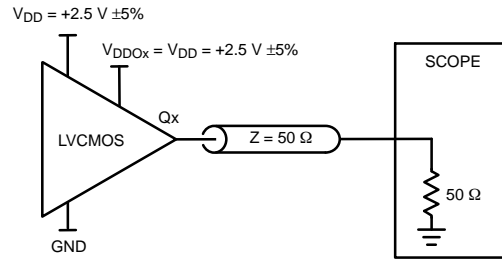
NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- XTAL_IN can be overdriven relative to a signal a crystal would provide.
- Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at $V_{DDOx}/2$.
- This parameter is defined in accordance with JEDEC Standard 65.
- These parameters are guaranteed by characterization. Not tested in production. See Parameter Measurement Information
- AC parameters for LVCMOS are dependent upon output capacitive loading.

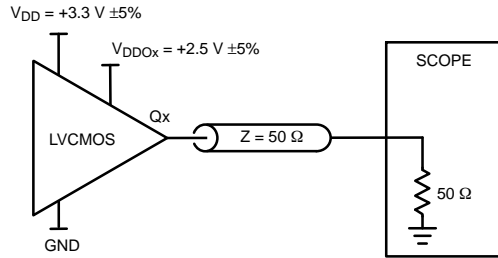
PARAMETER MEASUREMENT INFORMATION



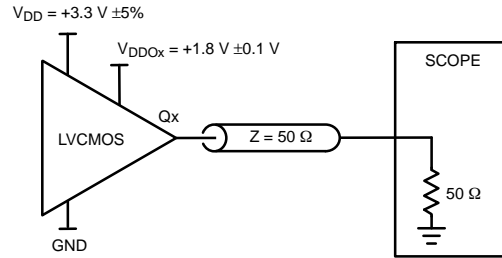
3.3 V Core / 3.3 V Output Load AC Test Circuit



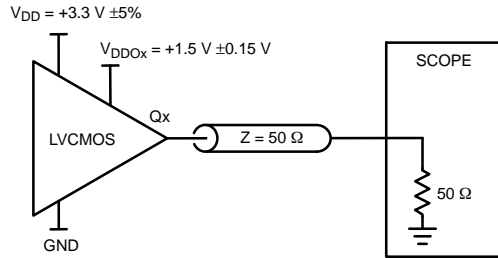
2.5 V Core / 2.5 V Output Load AC Test Circuit



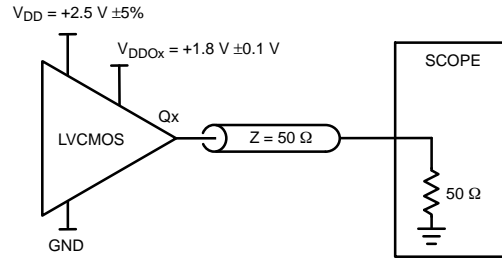
3.3 V Core / 2.5 V Output Load AC Test Circuit



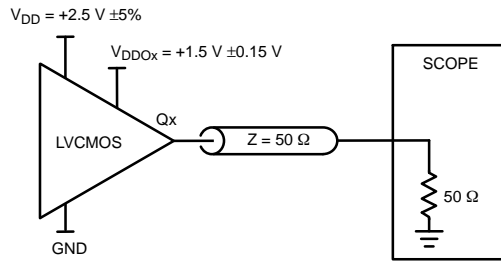
3.3 V Core / 1.8 V Output Load AC Test Circuit



3.3 V Core / 1.5 V Output Load AC Test Circuit



2.5 V Core / 1.8 V Output Load AC Test Circuit



2.5 V Core / 1.5 V Output Load AC Test Circuit

Figure 3. Operational Supply and Termination Test Conditions

PARAMETER MEASUREMENT INFORMATION

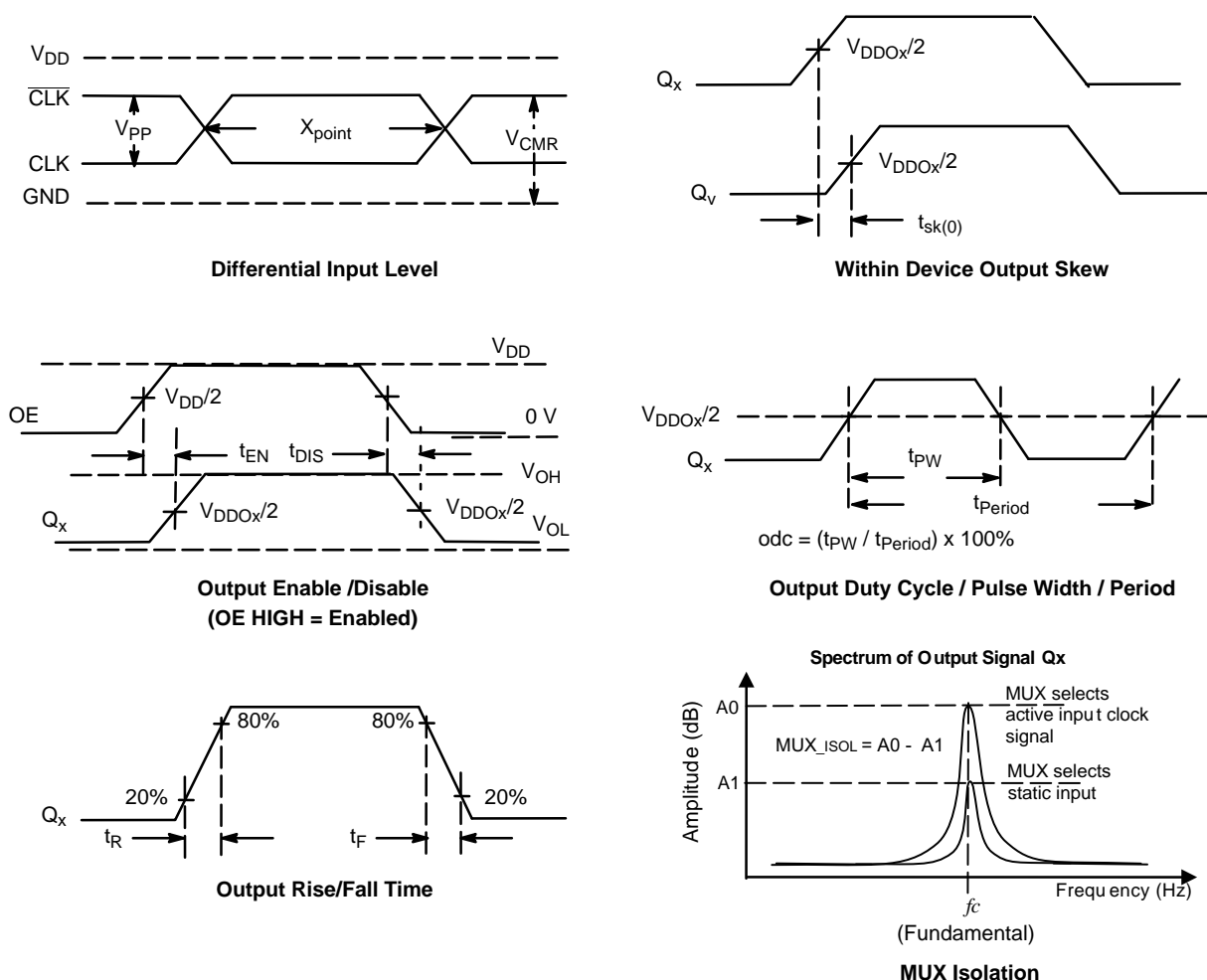


Figure 4. Operational Waveforms and MUX Input Isolation Plot

APPLICATION INFORMATION

Recommendations for Unused LVCMOS Output Pins

Inputs:

CLK/CLK Inputs

For applications not requiring the use of the differential input, both CLK and $\overline{\text{CLK}}$ can be left floating. Though not required, but for additional protection, a 1 k Ω resistor can be tied from CLK to ground.

Crystal Inputs

For applications not requiring the use of the crystal oscillator input, both XTAL_IN and XTAL_OUT can be left floating. Though not required, but for additional protection, a 1 k Ω resistor can be tied from XTAL_IN to ground.

LVCMOS Control Pins

All control pins have internal pulldowns; additional resistance is not required but can be added for additional protection. A 1 k Ω resistor can be used.

Power Supplies

VDD is the power supply for the core and input circuitry.

VDDOA and **VDDOB** are two separate positive power supplies for two banks of outputs:

VDDOA pins 2 and 6 are connected internally for outputs Q0 – Q1.

VDDOB pins 14 and 18 are connected internally for outputs Q2 – Q4.

Differential Input with Single-Ended Interconnect

Refer to Figure 5 to interconnect a single-ended to a Differential Pair of inputs. The reference bias voltage $V_{REF} = V_{DD}/2$ is generated by the resistor divider of R3 and R4. Bypass capacitor (C1) can filter noise on the DC bias. This bias circuit should be located as close to the input pin as possible. Adjust R1 and R2 to common mode voltage of the signal input swing to preserve duty cycle.

This configuration requires that the sum of the output impedance of the driver (R_o) and the series resistance (R_s) equals the transmission line impedance. In addition, matched termination by R1 and R2 will attenuate the signal

amplitude in half. Termination may be done by using R_s or by using R1 and R2. First, $R_s = 0$ and then R3 and R4 in parallel should equal the transmission line impedance. For most 50 Ω applications, R1 and R2 can be 100 Ω . The differential input can handle full rail LVC MOS signaling, but it is recommended that the amplitude be reduced. The datasheet specifies a differential amplitude which needs to be doubled for a single ended equivalent stimulus. V_{ILmin} cannot be less than -0.3 V and V_{IHmax} cannot be more than $V_{DD} + 0.3$ V. The datasheet specifications are characterized and guaranteed by using a differential signal.

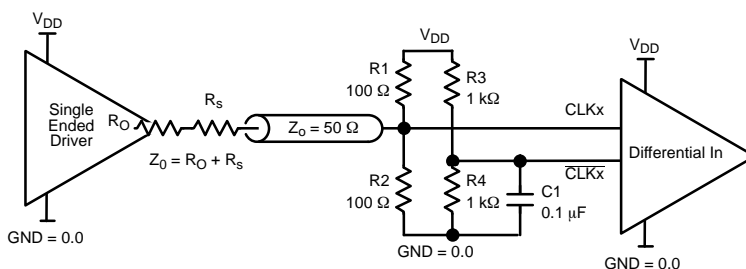


Figure 5. Differential Input with Single-ended Interconnect

Crystal Input Interface

The device has been characterized with 18 pF parallel resonant crystals. The capacitor values, C1 and C2, shown in Figure 6 below as 15 pF were determined using an 18 pF parallel resonant crystal and were chosen to minimize the ppm error. The optimum C1 and C2 values can be slightly adjusted for different board layouts.

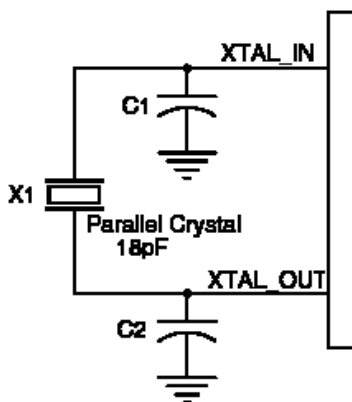


Figure 6. Crystal Input Interface

CLOCK Overdriving the XTAL Interface

The XTAL_IN input can accept a single-ended LVC MOS signal through an AC coupling capacitor. A general LVC MOS interface diagram is shown in Figure 7 and a general LVPECL interface in Figure 8. The XTAL_OUT pin must be left floating. The maximum amplitude of the input signal should not exceed 2 V and the input edge rate can be as slow as 10 ns. This configuration requires that the output impedance of the driver (R_o) plus the series resistance (R_s) equals the transmission line impedance. In addition, matched termination at the crystal input will attenuate the signal in half. This can be done in one of two ways. First, R1 and R2 in parallel should equal the transmission line impedance. For most 50 Ω applications, R1 and R2 can be 100 Ω . This can also be accomplished by removing R1 and making R2 50 Ω . By overdriving the crystal oscillator, the device will be functional, but note, the device performance is guaranteed by using a quartz crystal.

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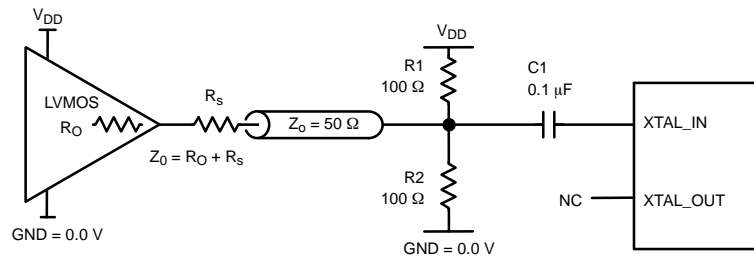


Figure 7. General Diagram for LVC MOS Driver to XTAL Input Interface Use R_S or R_1 / R_2

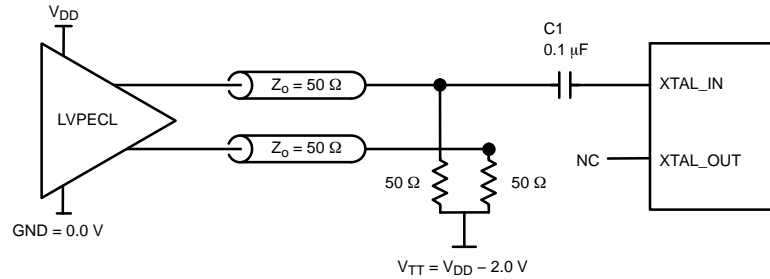


Figure 8. General Diagram for LVPECL Driver to XTAL Input Interface

Differential Clock Input Interface

The CLK / $\overline{\text{CLK}}$ accept LVDS, LVPECL, SSTL, HCSL differential signals. Signals must meet the V_{PP} and V_{CMR} input requirements. Figures 9 to 13 show interface examples for the CLK / $\overline{\text{CLK}}$ input with built-in 50 Ω terminations driven by the most common driver types. The

input interfaces suggested here are examples only. If the driver is from another vendor, use their termination recommendation. Please consult with the vendor of the driver component to confirm the driver termination requirements.

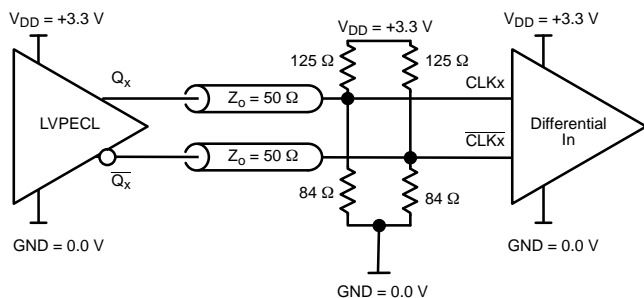


Figure 9. CLK / $\overline{\text{CLK}}$ Input Driven by 3.3 V LVPECL Driver (Thevenin Parallel Termination)

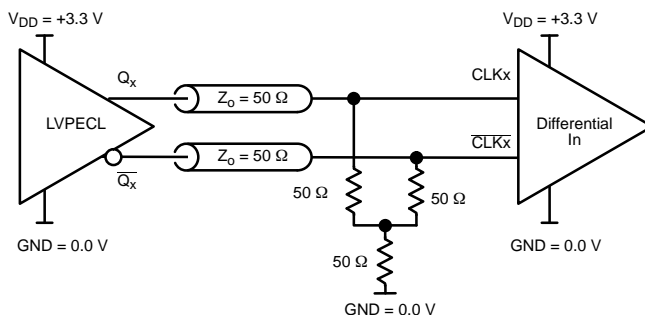


Figure 10. CLK / $\overline{\text{CLK}}$ Input Driven by 3.3 V LVPECL Driver ("Y" Parallel Termination)

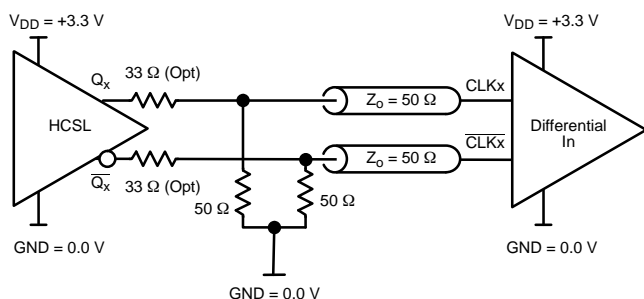


Figure 11. CLK / $\overline{\text{CLK}}$ Input Driven by a 3.3 V HCSL Driver

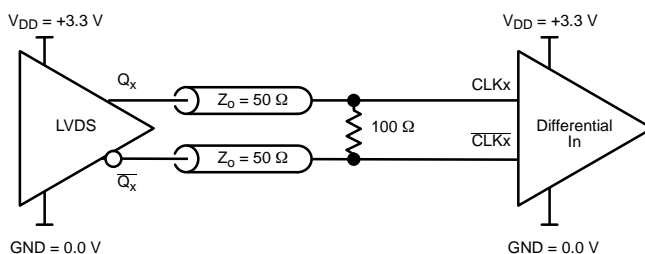


Figure 12. CLK / $\overline{\text{CLK}}$ Input Driven by 3.3 V LVDS Driver

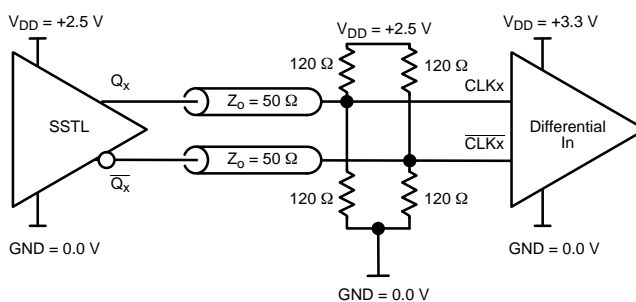


Figure 13. CLK / $\overline{\text{CLK}}$ Input Driven by 2.5 V SSTL Driver

VFQFN EPAD Thermal Release Path

In order to maximize both the removal of heat from the package and the electrical performance, a land pattern must be incorporated on the Printed Circuit Board (PCB) within the footprint of the package corresponding to the exposed metal pad or exposed heat slug on the package, as shown in Figure 14. The solderable area on the PCB, as defined by the solder mask, should be at least the same size/shape as the exposed pad/slug area on the package to maximize the thermal/electrical performance. Sufficient clearance should be designed on the PCB between the outer edges of the land pattern and the inner edges of pad pattern for the leads to avoid any shorts. While the land pattern on the PCB provides a means of heat transfer and electrical grounding from the package to the board through a solder joint, thermal vias are necessary to effectively conduct from the surface of the PCB to the ground plane(s). The land pattern must be connected

to ground through these vias. The vias act as “heat pipes”. The number of vias (i.e. “heat pipes”) is application specific and dependent upon the package power dissipation as well as electrical conductivity requirements. Thus, thermal and electrical analysis and/or testing are recommended to determine the minimum number needed. Maximum thermal and electrical performance is achieved when an array of vias is incorporated in the land pattern. It is recommended to use as many vias connected to ground as possible. It is also recommended that the via diameter should be 12 to 13 mils (0.30 to 0.33 mm) with 1 oz copper via barrel plating. This is desirable to avoid any solder wicking inside the via during the soldering process which may result in voids in solder between the exposed pad/slug and the thermal land. Precautions should be taken to eliminate any solder voids between the exposed heat slug and the land pattern. Note: These recommendations are to be used as a guideline only.

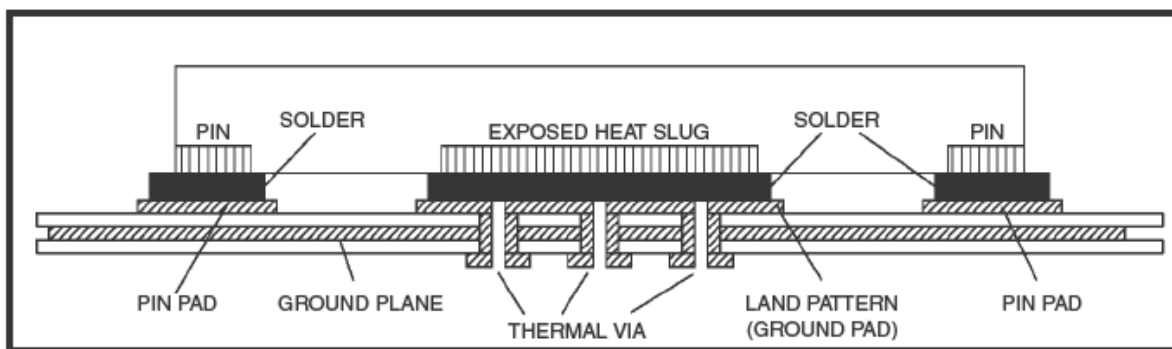


Figure 14. Suggested Assembly for Exposed Pad Thermal Release Path – Cut-away View (not to scale)

ORDERING INFORMATION

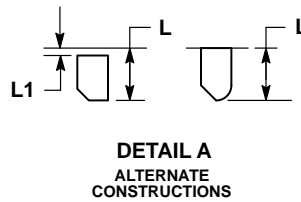
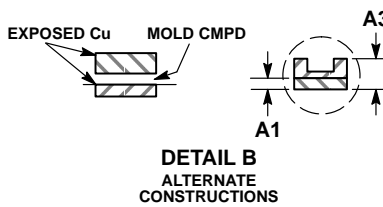
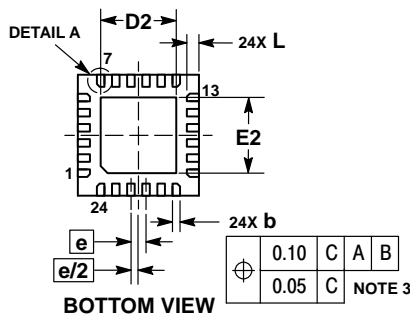
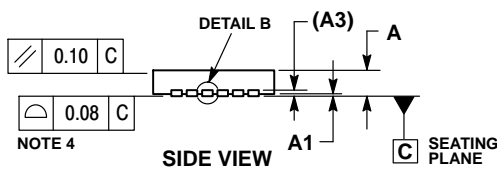
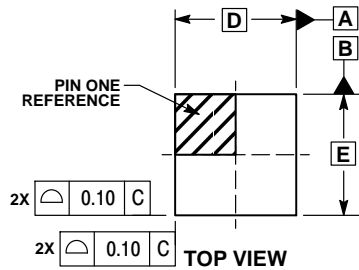
Device	Package	Shipping†
NB3F8L3005CMNTXG	QFN24 (Pb-Free)	3000 / Tape & Reel
NB3F8L3005CMNTBG		1000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NB3F8L3005C

PACKAGE DIMENSIONS

QFN24, 4x4, 0.5P
CASE 485DJ
ISSUE O

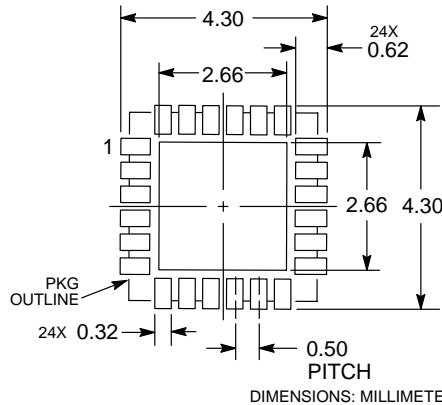


NOTES:


1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM THE TERMINAL TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

MILLIMETERS		
DIM	MIN	MAX
A	0.80	0.90
A1	0.00	0.05
A3	0.20	REF
b	0.20	0.30
D	4.00	BSC
D2	2.40	2.60
E	4.00	BSC
E2	2.40	2.60
e	0.50	BSC
L	0.30	0.50
L1	---	0.15

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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